

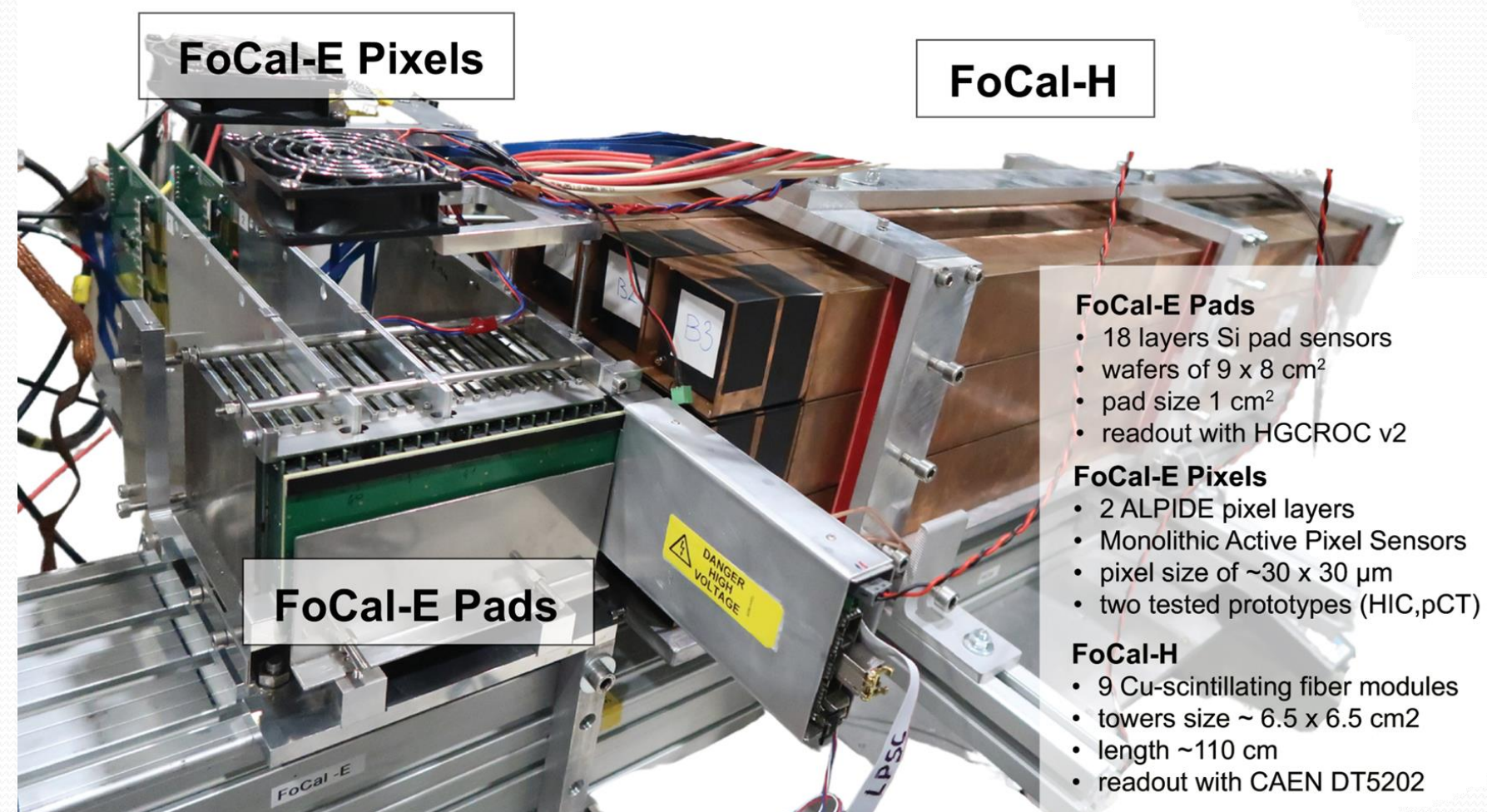
HGCROC v2 readout chip characterization and radiation tolerance for FoCal-E pad detector in ALICE

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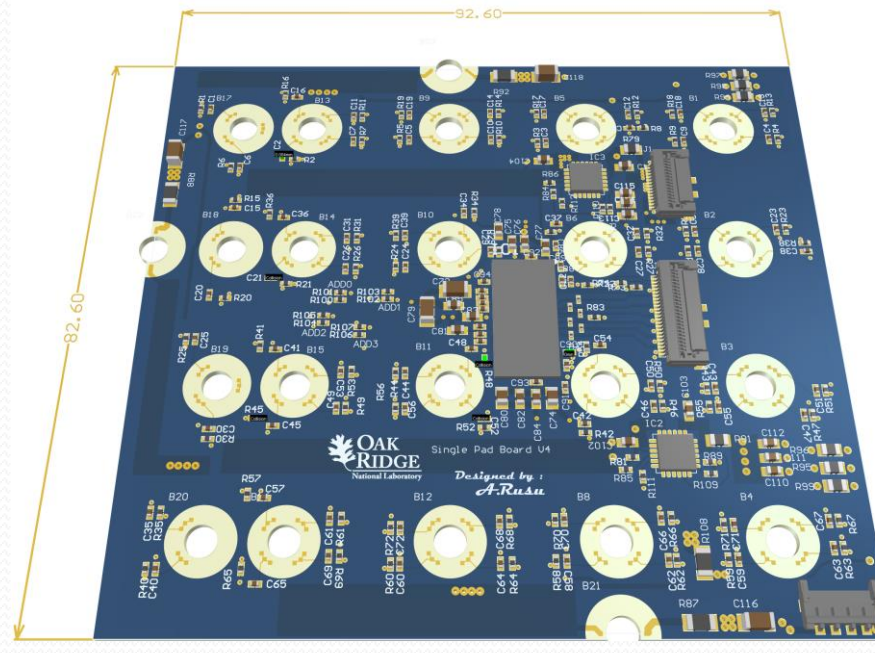
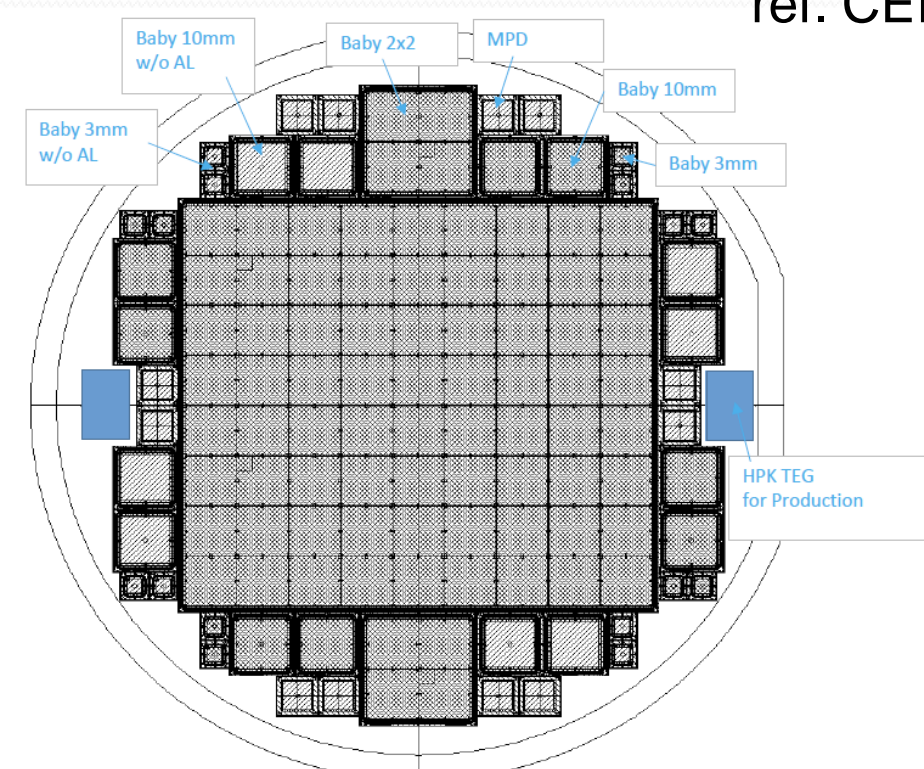
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Introduction: FoCal E-pad detector

- ◆ The Forward Calorimeter (FoCal) detector is scheduled for installing in the ALICE experiment for the LHC-Run4 upgrade (2029-2032).
- ◆ The FoCal-E is a detector based on a Si sensor and tungsten to measure electromagnetic/hadronic shower profile in the forward region.



ref. CERN-LHCC-2024-004 ; ALICE-TDR-022

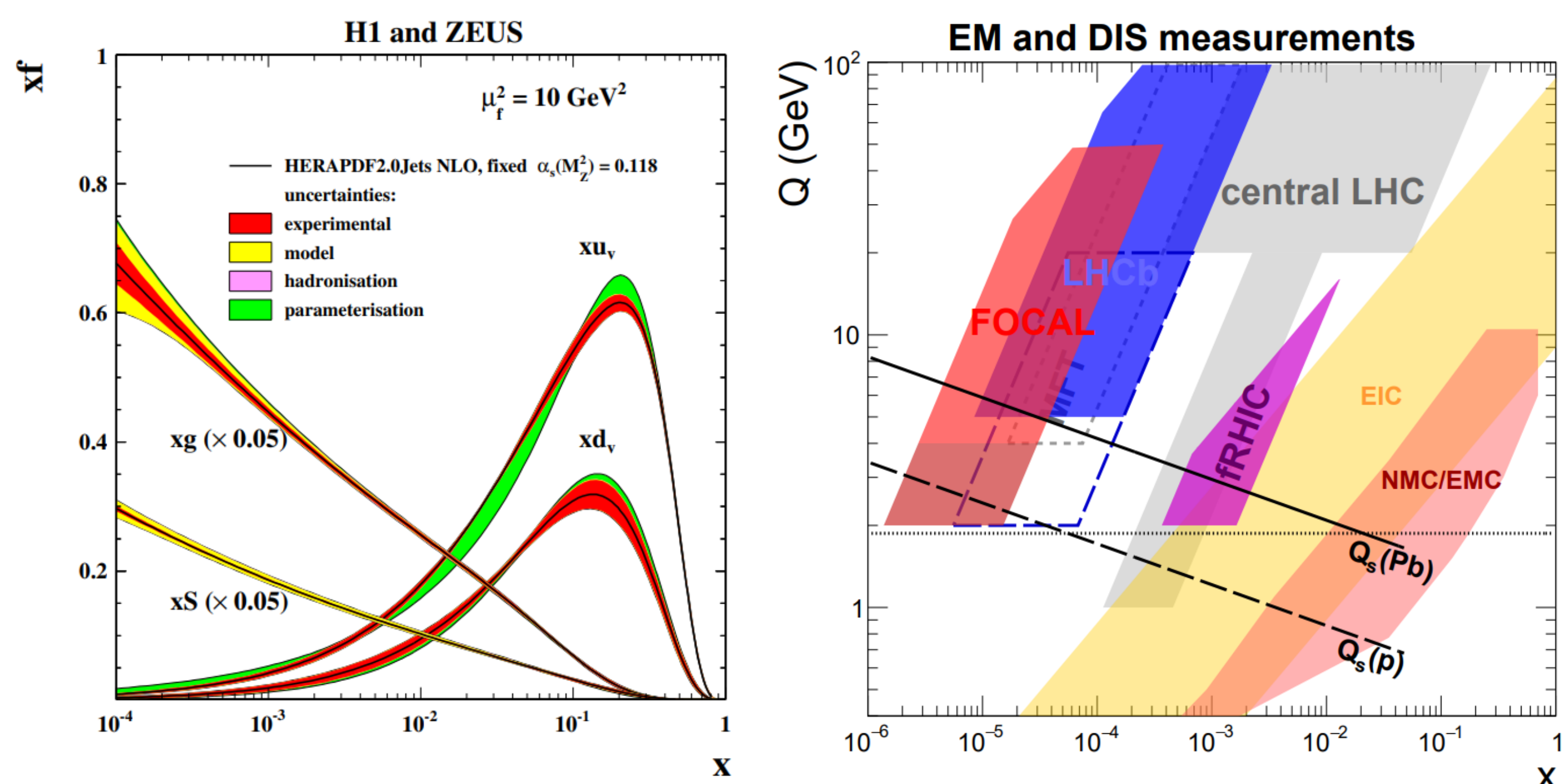


The PCB with HGCROC for a single pad Si sensor

Hamamatsu p-type, S162111-1665 main sensor and Layout

- ◆ Si pad sensor has $9 \times 8 = 72$ main cells (pad size 1 cm^2) and two calibration cells
Thickness : $320 \pm 15 \mu\text{m}$
Full depletion voltage : min 120 V / max 270 V
- ◆ HGCROC (developed by OMEGA) dynamic range :
Low Range (1MIP \approx 2 MeV) : ADC (Analog to Digital Converter), 10 bits 1024ch
High Range ($\sim 1 \text{ TeV}$) : TOT (Time Over Threshold), 12 bits 4096ch
ref. CERN-LHCC-2017-023 ; CMS-TDR-019
- ◆ It's important to check the HGCROC chip performance and the variability.

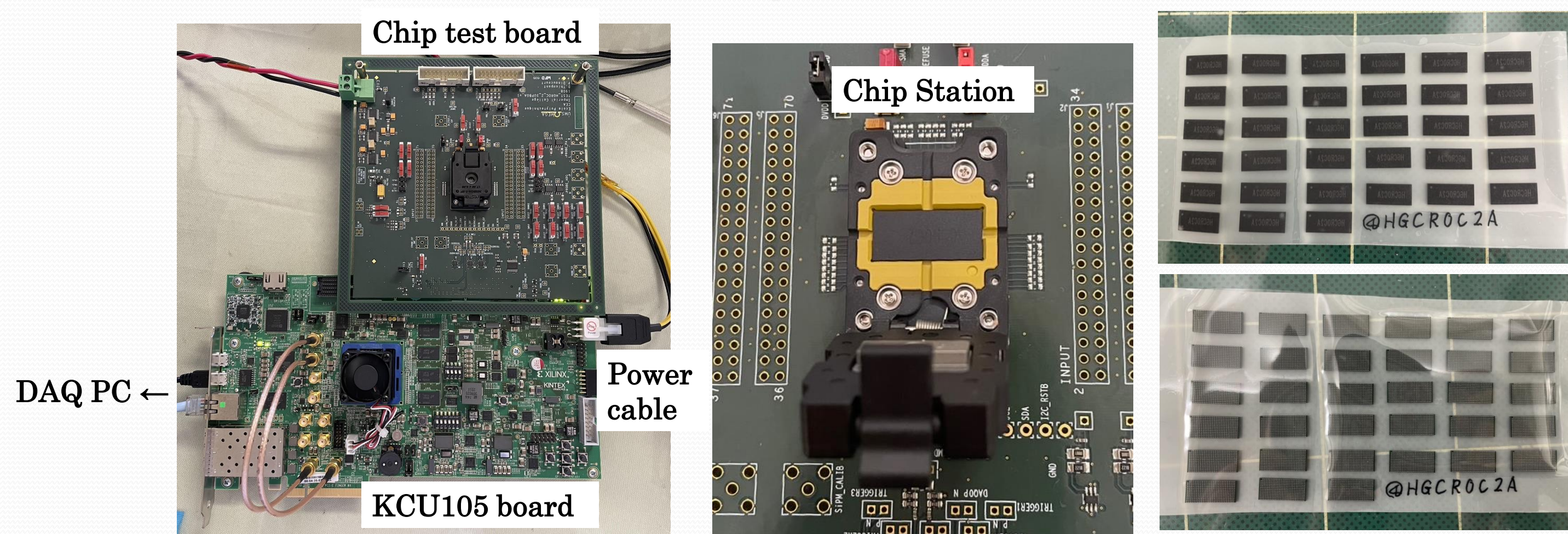
Physics motivation: elucidate small-x



Cf. A Forward Calorimeter (FoCal) in the ALICE experiment <https://cds.cern.ch/record/2719928/files/LHCC-1-036.pdf>

- ◆ Nuclear Parton Distribution function (nPDF) for gluon increases at small x
- ◆ Only known up to $x \approx 10^{-4}$, and even smaller values are not known
- ◆ FoCal aims to measure nPDF for gluons at small x from 10^{-6} to 10^{-4} and gluon saturation

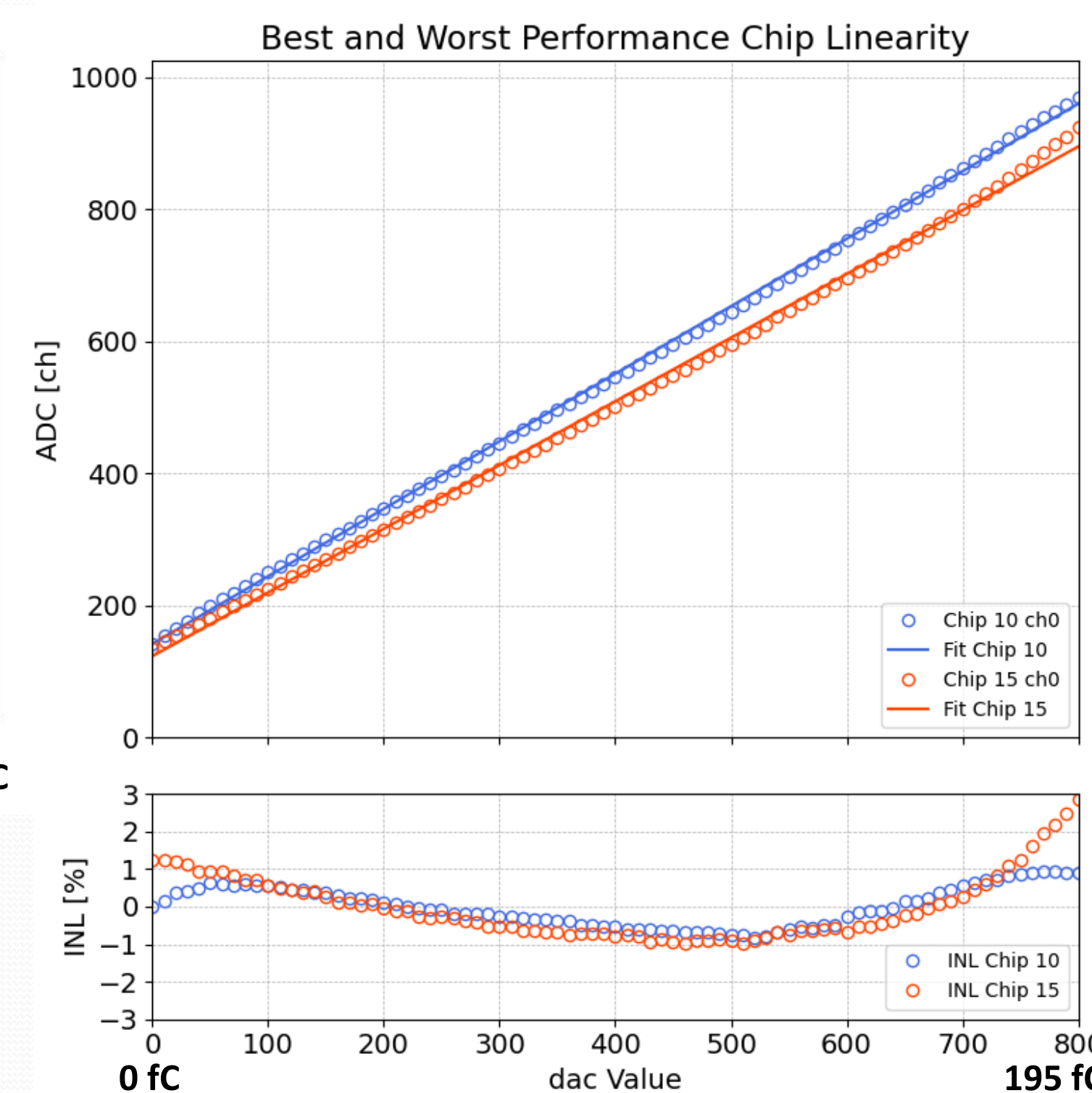
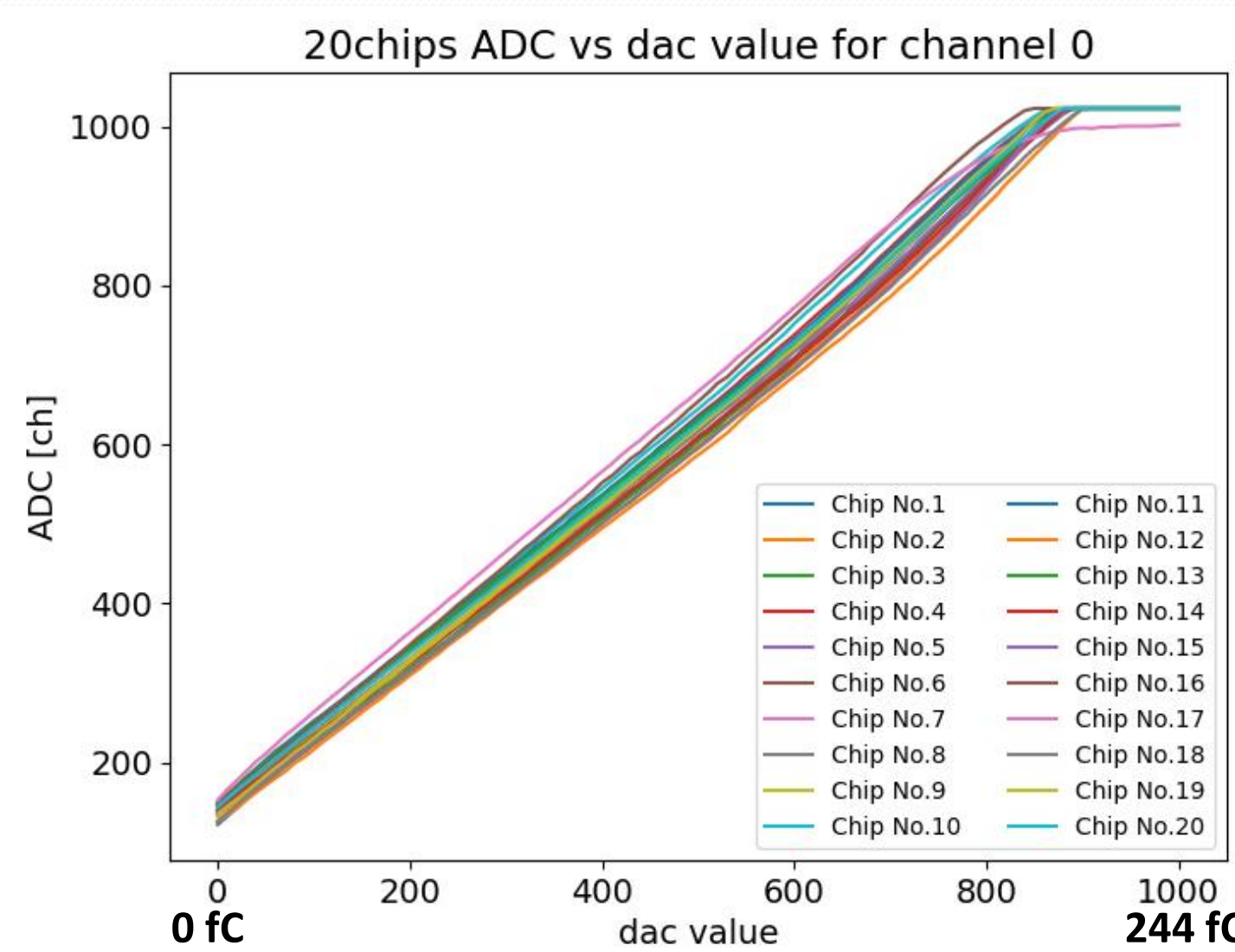
Experimental Setup



HGCROC2A chip package

- ◆ Put the HGCROC chip into the socket of chip station
- ◆ Easily communicate with the chip without soldering
- ◆ New HGCROC2 and 2A were packaged in Japan (total 344 chips)
*2A is a slightly upgraded version of 2
- ◆ ADC and TOT values were measured by DAC scan with internal charge injection.
- ◆ Preamp Gain Settings :
 $C_f=300 \text{ fF}$, $C_{f_comp}=100 \text{ fF}$, $R_f=25 \text{ k}\Omega$ (high gain, $0.22 \text{ fC} / 1 \text{ ch ADC}$)

Result: ADC Linearity



- ◆ DAC scan results with low injection
- ◆ Fitted range: 0 to 800 (0 ~ 195 fC)
- ◆ Best chip (blue) linearity :
 $-1\% \sim +1\% (< 2\%)$
- ◆ Worst chip (red) linearity :
 $-1\% \sim +3\% (< 4\%)$
- ◆ HGCROC2 Datasheet :
 $-3\% \sim +1\% (< 4\%)$

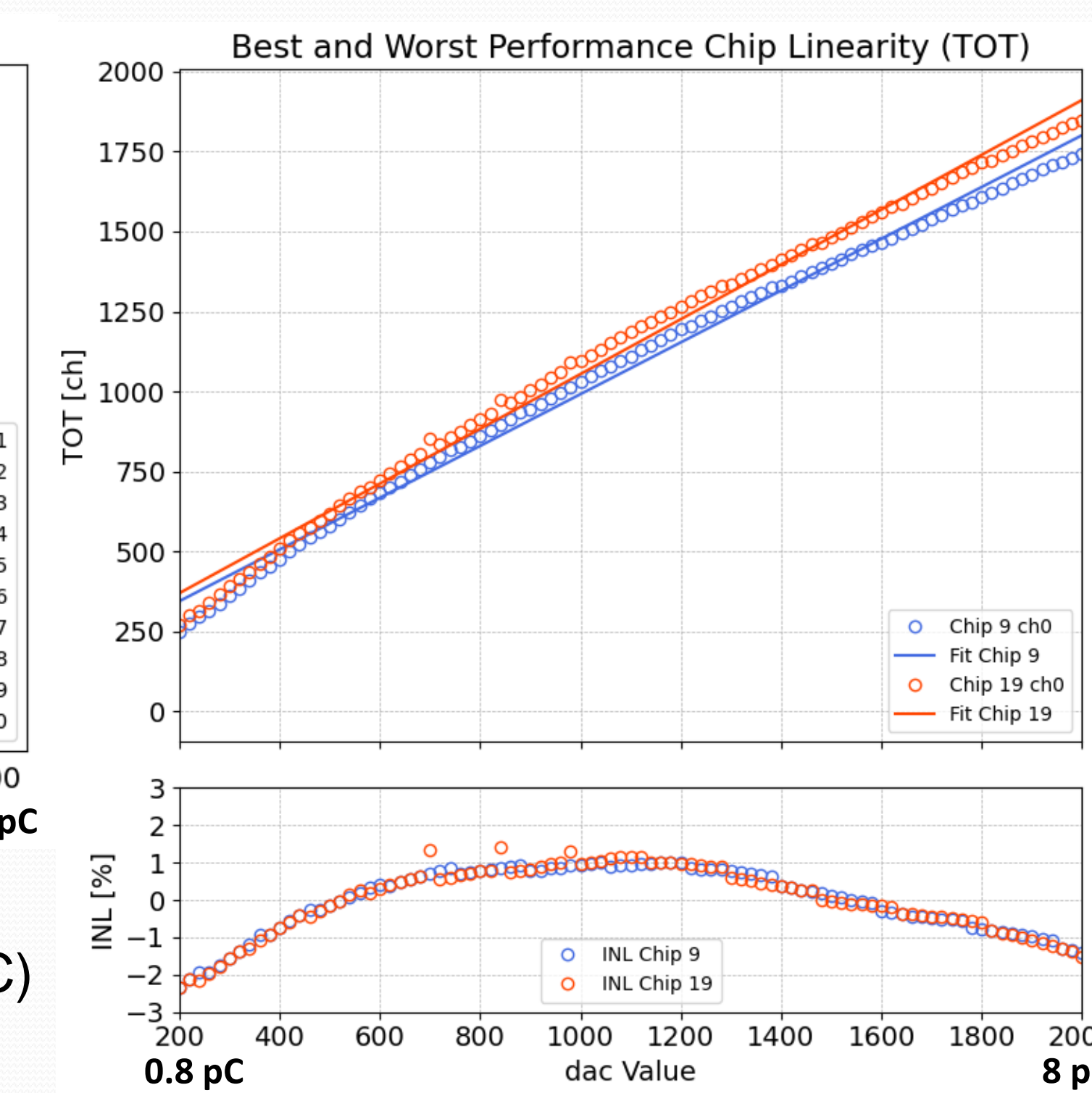
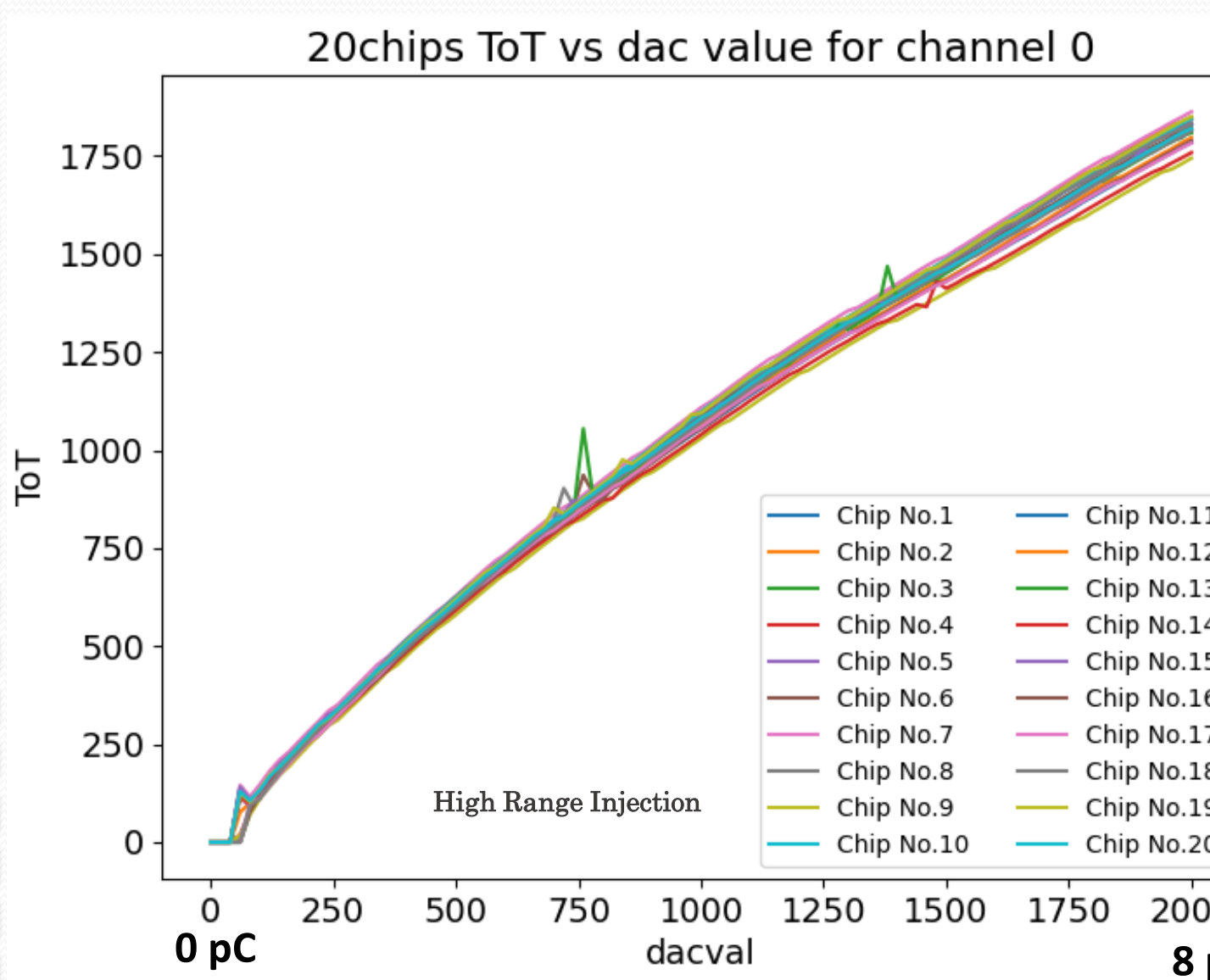
$$INL = \frac{\text{data val} - \text{fit val}}{1024} \times 100 [\%]$$

(Integral Non-Linearity)

ADC : 10bits

→All chips ADC satisfies FoCal's requirements ($< 4\%$).

Result: TOT Linearity



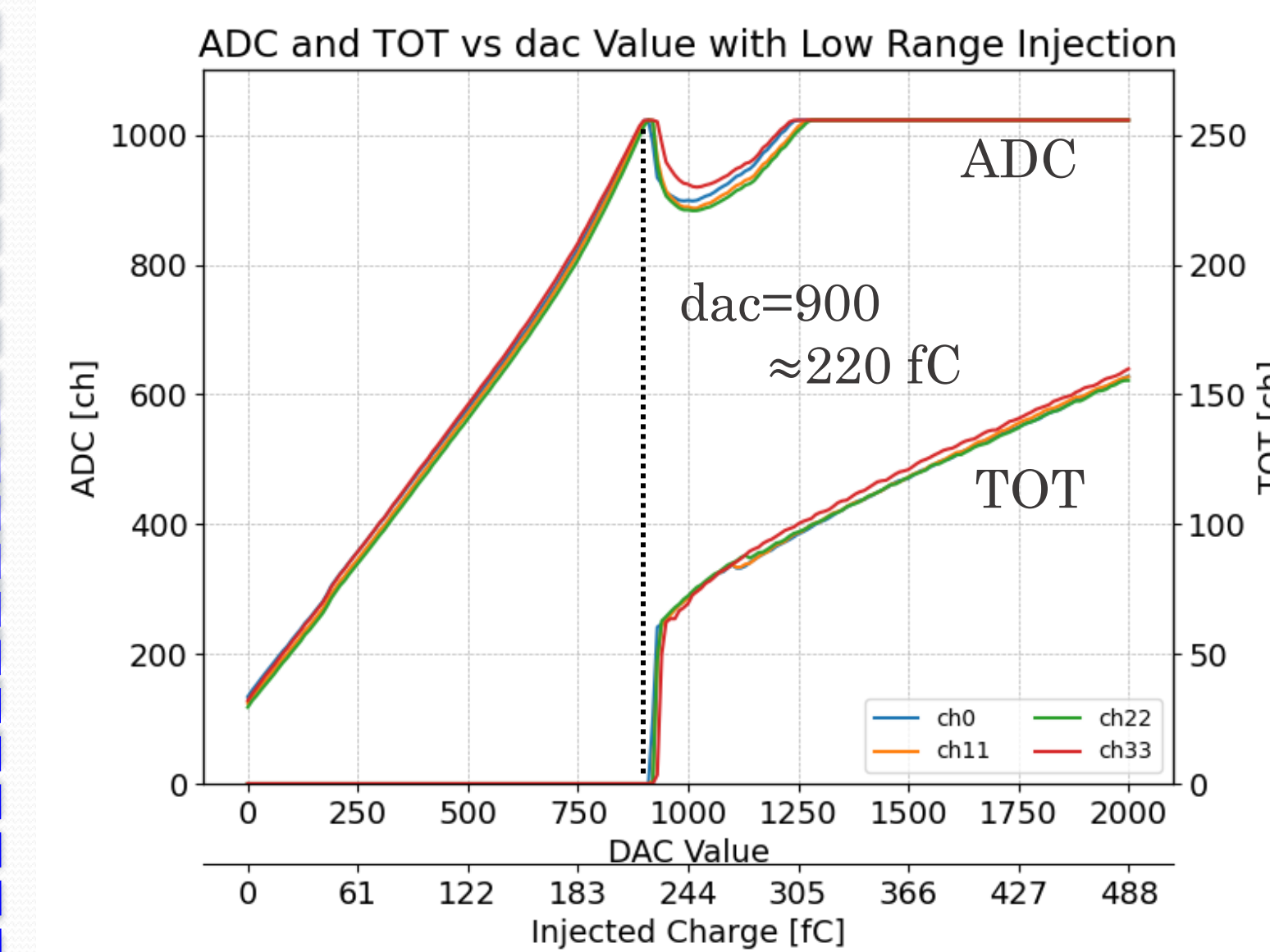
- ◆ DAC scan results with high injection
- ◆ Fitted range: 200 to 2000 (0.8 ~ 8 pC)
- ◆ Due to a test board issue, 36~71ch could not be tested
- ◆ Small channel-to-channel variation
- ◆ The Best and Worst chip linearity :
 $-2\% \sim +1\% (< 3\%)$
- ◆ HGCROC2 Datasheet :
 $-2\% \sim +1\% (< 3\%)$

$$INL = \frac{\text{data val} - \text{fit val}}{4096} \times 100 [\%]$$

TOT : 12bits

→All chips TOT also satisfies FoCal's requirements ($< 3\%$).

Result: Gap between ADC and TOT



- ◆ TOT starts when ADC saturates
ADC range : 0 ~ 220 fC
TOT range : 220 fC ~ 8 pC
- ◆ When the TOT stands up, the ADC gets warped.
→ Cannot have overlap
→ Improvements planned for HGCROC3

Summary and Future Plan

- ◆ Linearity of all chips was sufficient for FoCal.
- ◆ Evaluate the performance by using external charge injection
- ◆ Performance study for the irradiated chip.
- ◆ Establish a test system for 2000 chips.
- ◆ Compare between HGCROC2 and HGCROC3 chips
→Set up the test environment for HGCROC3 chip